









PRODUCT DATASHEET



- ► DC-In Solid State Relay
- ► SMD7 Low Profile
- ► Random Phase TRIAC Output

TDRX223(SL)(T1)-GV





TDRX223(SL) Series

DESCRIPTION:





The TDRX223(SL) series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a monolithic silicon random-phase photo TRIAC to drive a power TRIAC in a plastic DIP7 package with SMD7 Low Profile lead forming option.

- Solenoid/valve controls
- Lighting controls

APPLICATIONS:

- Motor controls
- Temperature controls
- Static AC power switches
- Solid state relays
- Interfacing microprocessors to 115 to 240VAC peripherals

FEATURES:

- High isolation 5000Vrms
- DC input with TRIAC output
- Operating temperature range -40°C to +85°C
- **REACH & RoHS compliance**
- MSL class 1
- **Regulatory Approvals:**
 - UL UL1577
 - VDE EN60747-5-5 (VDE0884-5)
 - CQC GB4943.1, GB8898
 - cUL CSA Component Acceptance Service Notice 5A
- Packing: 1000pcs/reel











Release Date: 24 June 2025 Version: A00



NAMING & ORDERING INFORMATION:

Naming Information:

TDR X 223 (SL) (T1) - G V				
TDRX223	Part Number			
×	Selection: On-State RMS Current (X=0~3)			
SL	Lead Form Option: SMD7 Low Profile			
T1	Selection: Tape and Reel Option (T1(default)/T2)			
G	Green Option			
V	VDE Option			

Ordering Information:

TDR<u>X</u>223(SL)(T1)-GV

 \underline{X} = Selection: On-State RMS Current (X=0~3)

Part Number	Symbol			Unit	Test Condition	
Part Number	Зуппоп	Min.	Тур.	Max.	Ullit	rest condition
TDR0223(SL)(T1)-GV	IT _(RMS) *			0.3	А	I _{TSM} =3A ** P _W =100μs, 120pps
TDR1223(SL)(T1)-GV				0.6		I _{TSM} =6A P _W =100μs, 120pps
TDR2223(SL)(T1)-GV				0.9		I _{TSM} =9A P _W =100μs, 120pps
TDR3223(SL)(T1)-GV				1.2		I _{TSM} =12A P _W =100μs, 120pps

^{*} $IT_{(RMS)}$ = On-State RMS Current

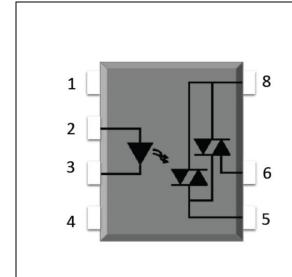
Version No.	Original Release Date		
Rev: A00	29/08/2024		

^{**} I_{TSM} = Non-repetitive Surge Current



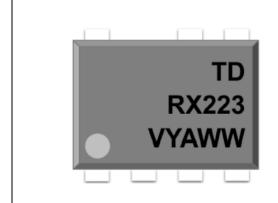
SCHEMATIC DIAGRAM & MARKING:

Schematic Diagram:



PIN Definition			
1	NC		
2	Anode		
3	Cathode		
4	NC		
5	Gate		
6	Terminal		
7	(Absent)		
8	Terminal		

Marking Information:



Marking Definition			
TD	Manufacturer Code		
RX223	Part Number		
V	VDE Applicable		
Υ	Fiscal Year		
А	Manufacturing Code		
ww	Work Week		

Labelling Information:



This product is manufactured, tested, and packed by



for more details, please visit www.tdled.com



ABSOLUTE CHARACTERISTICS:

Absolute Maximum Ratings:

Parameter	Symbol	Ratings	Unit		
		INPUT			
Forward Current		I _F	60	mA	
Peak Forward Current		I _{FP}	1*1	А	
Reverse Voltage		V _R	6	V	
Junction Temperature		Tj	125	°C	
Input Power Dissipation		Pı	100	mW	
	(OUTPUT			
Off-State Output Terminal Voltag	e	V _{DRM}	600	V	
	TDR0223		0.3		
0.01.000	TDR1223] .	0.6		
On-State RMS Current	TDR2223	I _{T(RMS)}	0.9	А	
	TDR3223		1.2		
	TDR0223		3		
Non-repetitive Surge Current	TDR1223]	6	А	
Pw=100μs, 120pps	TDR2223	- I _{TSM}	9		
	TDR3223		12		
Junction Temperature		Tj	125	°C	
	C	OMMON			
Total Power Dissipation		P _{tot}	400	mW	
Isolation Voltage		V _{iso}	5000 *2	Vrms	
Operating Temperature		T _{opr}	-40~+85	°C	
Storage Temperature		T _{stg}	-40~+125	°C	
Soldering Temperature		T _{sol}	260 for 10s max.	°C	

^{*1. 100}µs pulse, 100Hz frequency.

^{*2.} AC for 1 minute, R.H.= $40^{\circ}60\%$.



ELECTRICAL CHARACTERISTICS:

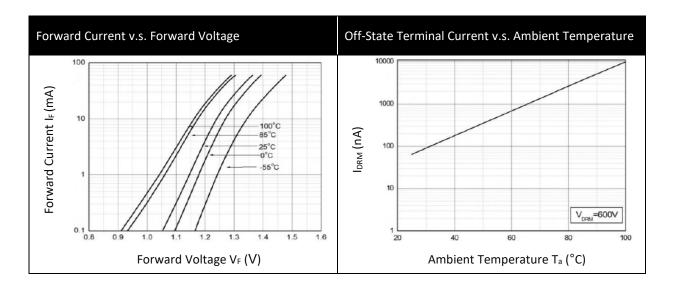
Electrical Optical Characteristics at T_a=25°C:

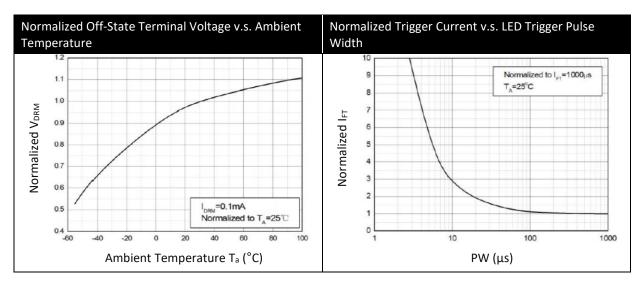
Parameter	Symbol		Values		Unit	Test Condition
raiailletei	Зуппоп	Min.	Тур.	Max.	UIIIL	rest condition
		INPU ⁻	Г			
Forward Voltage	V _F		1.24	1.4	V	I _F =10mA
Reverse Current	I _R			10	μΑ	V _R =6V
Input Capacitance	Cin		30		pF	V=0, f=1kHz
		OUTPL	JT			
Peak Off-State Current Either Direction	I _{DRM}			100	μΑ	V _{DRM} =600V I _F =0
On-State Terminal Voltage	V _{TM}		0.8	2.5	V	I _{TM} =Rated I _{TM}
Critical Rate of Rise of Off-State Voltage - Breakdown Voltage	dV/dt	1000			V	V _{PEAK} =600V *1
	TRANSFER CHARACTERISTICS					
LED Trigger Current	I _{FT}			10	mA	R _L =100Ω Terminal Voltage=6V
Holding Current	I _H			25	mA	
Isolation Resistance	R _{ISO}	10^12	10^14		Ω	DC=500V, 40~60% R.H.
Floating Capacitance	Сю		0.25	1	pF	V=0, f=1MHz

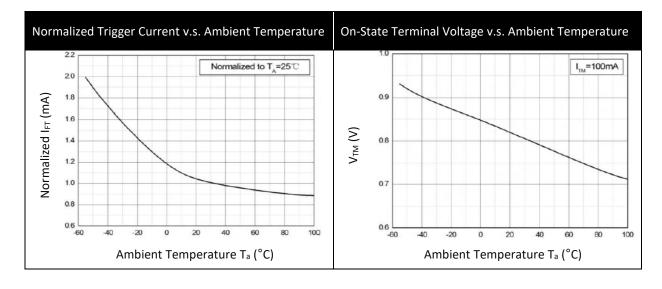
 $[{]m *1.}$ Test voltage must be applied within dV/dt rating.



CHARACTERISTIC CURVES:

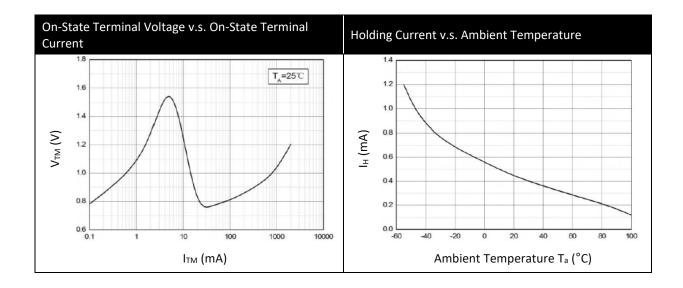


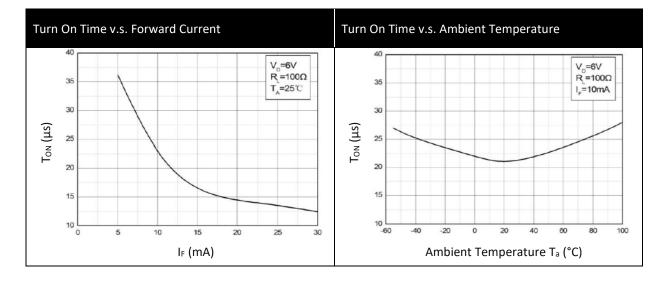






CHARACTERISTIC CURVES:

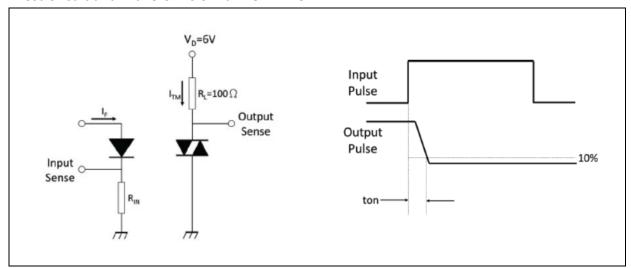




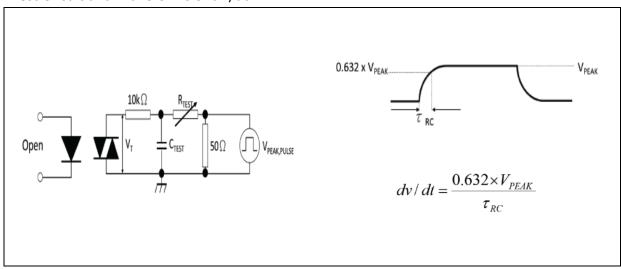


TEST CIRCUIT:

Test Circuit and Waveforms of Turn On Time:



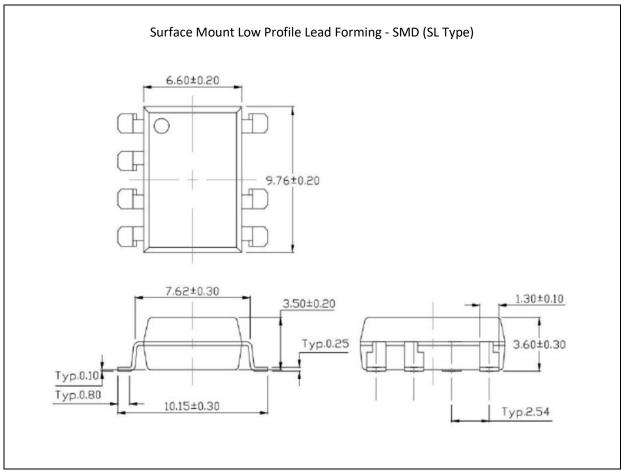
Test Circuit and Waveforms of dV/dt:





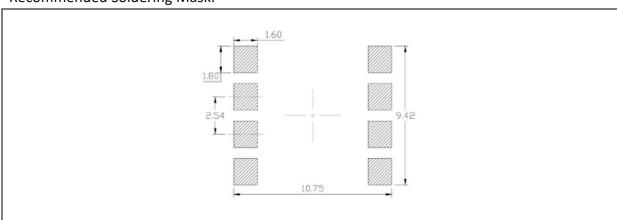
OUTLINE DIMENSION:

Package Dimension:



1. All dimensions are in millimetre (mm).

Recommended Soldering Mask:

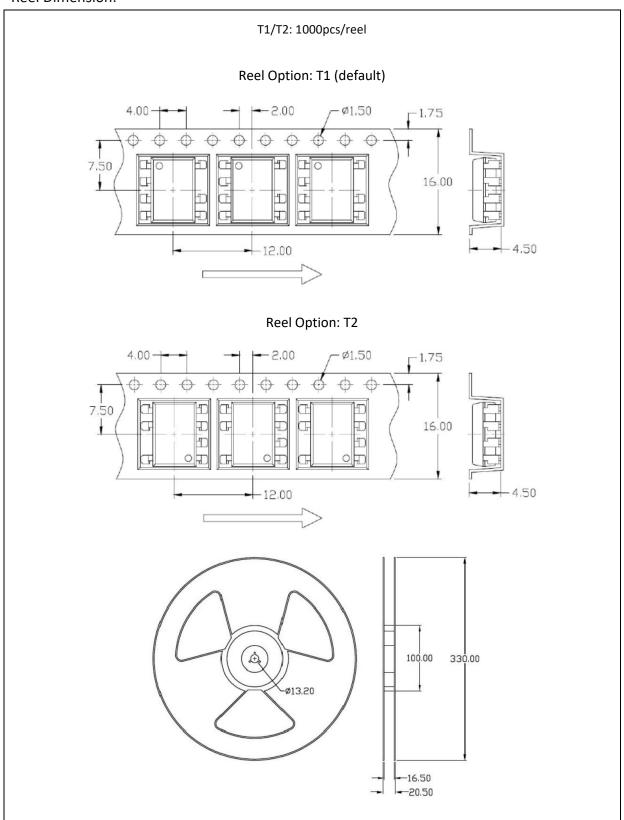


1. Dimensions are in millimetre (mm).



PACKING SPECIFICATION:

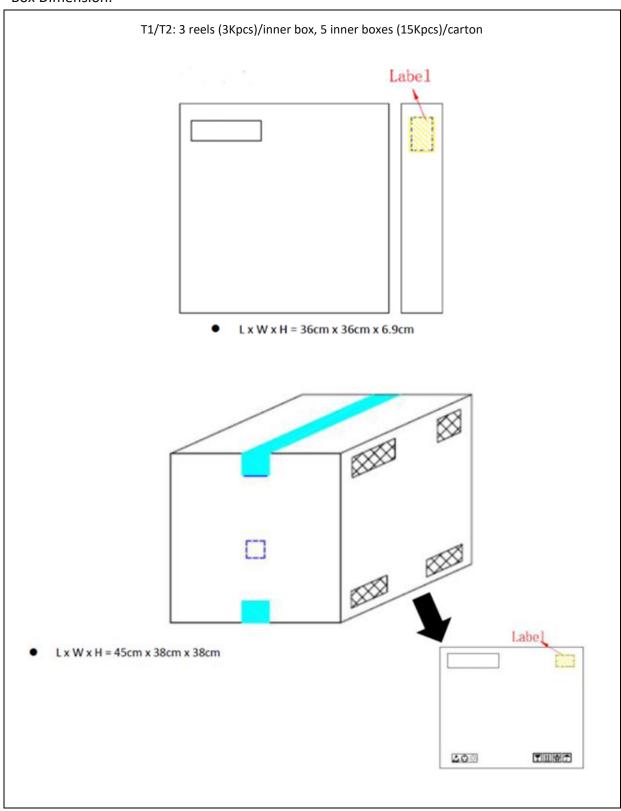
Reel Dimension:





PACKING SPECIFICATION:

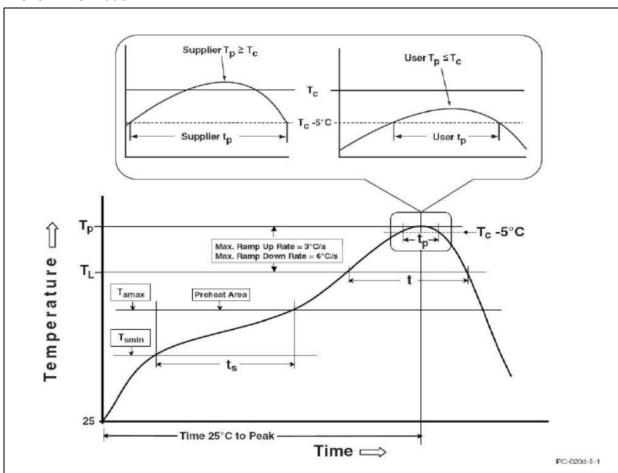
Box Dimension:





RECOMMENDED SOLDERING PROFILE:

Reflow Information:

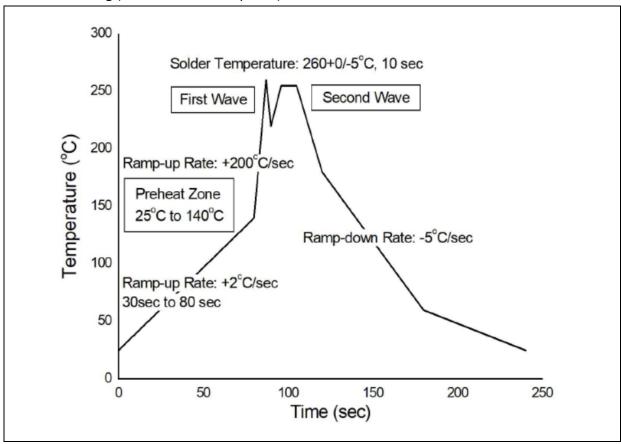


Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T _{smin})	100°C	150°C
Temperature Max. (T _{smax})	150°C	200°C
Time (t _s) from (T _{smin} to T _{smax})	60-120 seconds	60-120 seconds
Ramp-up Rate (t₁ to t₂)	3°C/second max.	3°C/second max.
Liquidous Temperature (T _L)	183°C	217°C
Time (t _L) Maintained Above (T _L)	60-150 seconds	60-150 seconds
Peak Body Package Temperature	235°C +0°C / -5°C	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max.	6°C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.



RECOMMENDED SOLDERING PROFILE:

Wave Soldering (JESD22-A111 Compliant):



Hand Soldering:

Soldering Temperature	380±5°C
Soldering Time	3 sec max.

Note:

- One time soldering is recommended for all soldering methods.
- Do not solder more than three times for IR reflow soldering.